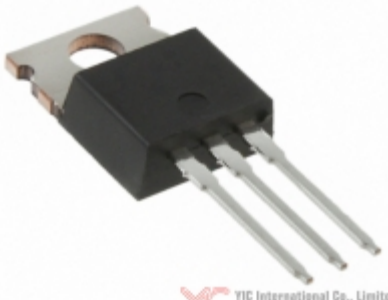




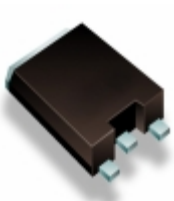





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|  | <h2 style="color: red;">IRFBG30PBF</h2> <p>Hersteller-Teilenummer: IRFBG30PBF</p> <p>Hersteller / Marke: Vishay / Siliconix</p> <p>Teil der Beschreibung: MOSFET N-CH 1000V 3.1A TO-220AB</p> <p>Datenblätter: 1.IRFBG30PBF.pdf 2.IRFBG30PBF.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 4021 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p> |
|  <p style="font-size: small;">YIC International Co., Limited.</p> | |
| <p>Image may be representation. See specs for product details.</p> | |

| Spezifikationen | |
|--|--|
| Teilenummer | IRFBG30PBF |
| Hersteller | Vishay / Siliconix |
| Beschreibung | MOSFET N-CH 1000V 3.1A TO-220AB |
| Kategorie | Diskrete Halbleiterprodukte > Transistoren-FETs, |
| Teilstatus | 4021 pcs Stock |
| Serie | - |
| Technologie | MOSFET (Metal Oxide) |
| Betriebstemperatur | -55°C ~ 150°C (TJ) |
| Befestigungsart | Through Hole |
| Verpackung / Gehäuse | TO-220-3 |
| Supplier Device-Gehäuse | TO-220AB |
| Verlustleistung (max) | 125W (Tc) |
| Typ FET | N-Channel |
| FET-Merkmal | - |
| Drain-Source-Spannung (Vdss) | 1000V (1kV) |
| Strom - Ununterbrochener Abfluss (Id) bei 25 ° C | 3.1A (Tc) |
| Rds On (Max) @ Id, Vgs | 5 Ohm @ 1.9A, 10V |
| VGS (th) (Max) @ Id | 4V @ 250µA |
| Gate Charge (Qg) (Max) @ Vgs | 80nC @ 10V |
| Eingabekapazität (Ciss) (Max) @ Vds | 980pF @ 25V |
| Antriebsspannung (Max Rds On, Min Rds On) | 10V |
| Vgs (Max) | ±20V |
| Verpackung | Tube |

IRFBG30PBF ist neu im Original, Suche IRFBG30PBF Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie IRFBG30PBF Vishay / Siliconix mit Garantie und Vertrauen.
 Anfrage IRFBG30PBF: Info@Y-IC.com

Sie können auch interessiert sein:

| | | | |
|--|---|---|---|
|  IRFBG30 Electro-Films (EFI) / Vishay MOSFET N-CH 1000V 3.1A TO-220AB |  IRFBG30PBF Electro-Films (EFI) / Vishay MOSFET N-CH 1000V 3.1A TO-220AB |  IRFC3004EB International Rectifier (Infineon Technologies) MOSFET N-CH WAFER |  IRFBG30 Vishay / Siliconix MOSFET N-CH 1000V 3.1A TO-220AB |
|  IRFBL3315 International Rectifier (Infineon Technologies) MOSFET N-CH 150V 21A SUPER D2PAK |  IRFBL10N60A IR IRFBL10N60A IR |  IRFC2604B International Rectifier (Infineon Technologies) MOSFET |  IRFBG20PBF Electro-Films (EFI) / Vishay MOSFET N-CH 1000V 1.4A TO-220AB |

heiße Teile

Mehr

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|--------------------------------|--------------------------------|-----------------------------|-----------------------------|--------------------------------|
| IRFBC40STRLPBF | IRFBC40STRR | IRFBC40STRR | IRFBC41LC | IRFBE20PBF |
| IRFBE20PBF | IRFBE20SPBF | IRFBE30L | IRFBE30L | IRFBE30LPBF-M |
| IRFBE30PBF | IRFBE30PBF | IRFBE30SPBF | IRFBE30SPBF | IRFBE30STRLPBF |
| IRFBE30STRLPBF | IRFBF20LPBF | IRFBF20LPBF | IRFBF20STRL | IRFBF20STRL |
| IRFBF20STRLPBF | IRFBF20STRLPBF | IRFBG20PBF | IRFBG20PBF | IRFBG30PBF |
| IRFBL10N60A | IRFC480LCD | IRFD010PBF | IRFD010PBF | IRFD020PBF |
| IRFD020PBF | IRFD110PBF | IRFD110PBF | IRFD120PBF | IRFD120PBF |
| IRFD12N06RLESM | IRFD210PBF | IRFD210PBF | IRFD214PBF | IRFD214PBF |
| IRFD220PBF | IRFD220PBF | IRFD244PBF | IRFD310PBF | IRFD310PBF |
| IRFD320PBF | IRFD320PBF | IRFD9010 | IRFD9010 | IRFD9014 |

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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